

HD74SSTV16857

1:1 14-bit SSTL_2 Registered Buffer

HITACHI

ADE-205-336F (Z)

Rev.6
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Description

The HD74SSTV16857 is a 14-bit registered buffer designed for 2.3 V to 2.7 V V_{cc} operation and LVC MOS reset ($\overline{\text{RESET}}$) input / SSTL_2 data (D) inputs and CLK input.

Data flow from D to Q is controlled by differential clock pins (CLK, $\overline{\text{CLK}}$) and the $\overline{\text{RESET}}$. Data is triggered on the positive edge of the positive clock (CLK), and the negative clock ($\overline{\text{CLK}}$) must be used to maintain noise margins. When $\overline{\text{RESET}}$ is low, all registers are reset and all outputs are low.

To ensure defined outputs from the register before a stable clock has been supplied, $\overline{\text{RESET}}$ must be held in the low state during power up.

Features

- Supports LVC MOS reset ($\overline{\text{RESET}}$) input / SSTL_2 data (D) inputs and CLK input
- Differential SSTL_2 (Stub series terminated logic) CLK signal
- Flow through architecture optimizes PCB layout
- Package type

Package type	Package code	Package suffix	Taping code
TSSOP-48 pin	TTP-48DB	T	EL (1,000 pcs / Reel)
TVSOP-48 pin	TTP-48DEV	N	EL (1,000 pcs / Reel)

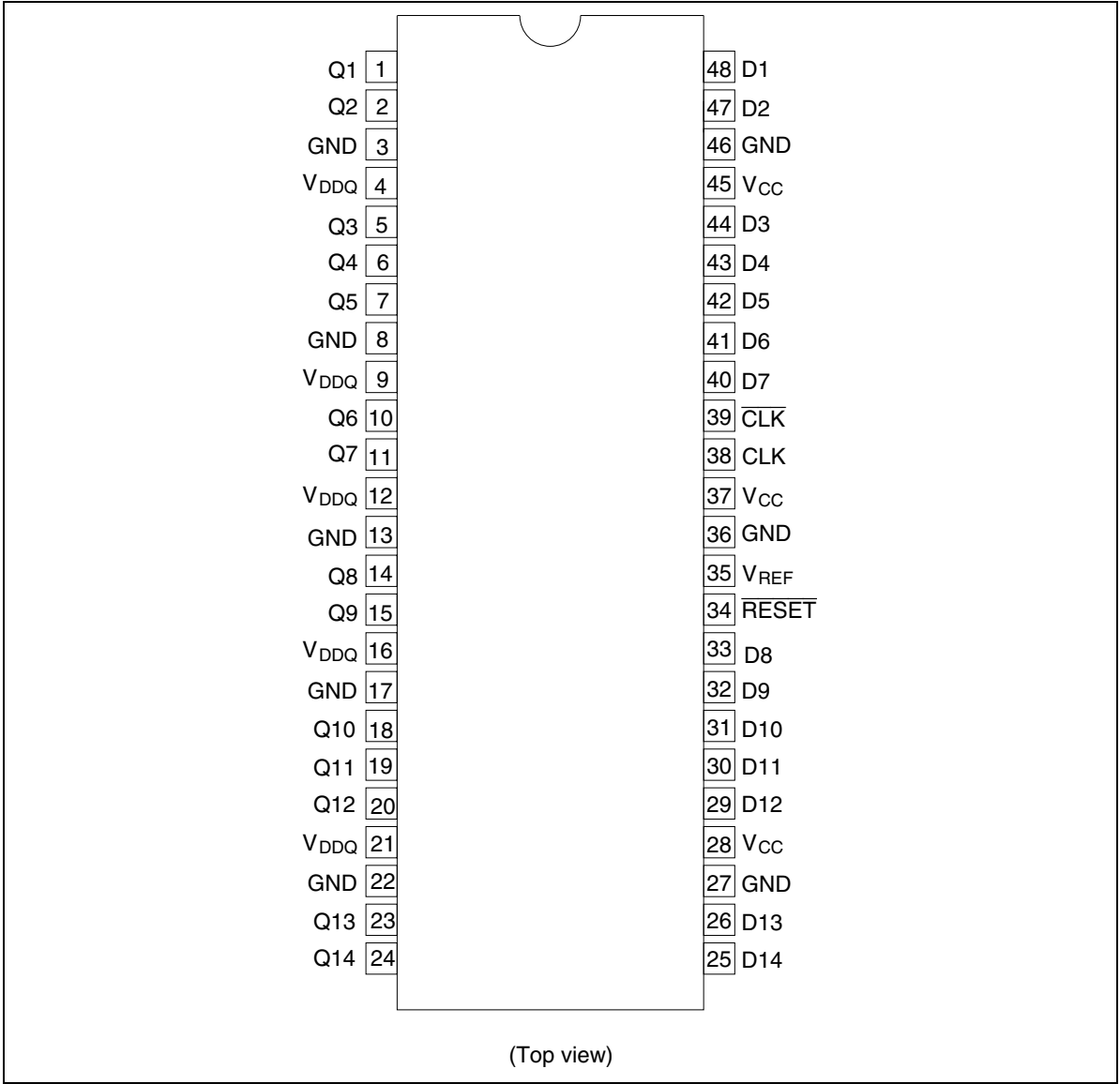
Function Table

Inputs				Output Q
RESET	CLK	CLK	D	
L	X	X	X	L
H	↓	↑	H	H
H	↓	↑	L	L
H	L or H	H or L	X	Q ₀ ⁻¹

- H : High level
L : Low level
X : Immaterial
↑ : Low to high transition
↓ : High to low transition

Note: 1. Output level before the indicated steady state input conditions were established.

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC} or V_{DDQ}	−0.5 to 3.6	V	
Input voltage ^{*1}	V_I	−0.5 to $V_{DDQ}+0.5$	V	
Output voltage ^{*1, 2}	V_O	−0.5 to $V_{DDQ}+0.5$	V	
Input clamp current	I_{IK}	±50	mA	$V_I < 0$ or $V_I > V_{CC}$
Output clamp current	I_{OK}	±50	mA	$V_O < 0$ or $V_O > V_{DDQ}$
Continuous output current	I_O	±50	mA	$V_O = 0$ to V_{DDQ}
V_{CC} , V_{DDQ} or GND current / pin	I_{CC} , I_{DDQ} or I_{GND}	±100	mA	
Maximum power dissipation at Ta = 55°C (in still air)	P_T	115	°C / W	TSSOP
Storage temperature	Tstg	−65 to +150	°C	

Notes: Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

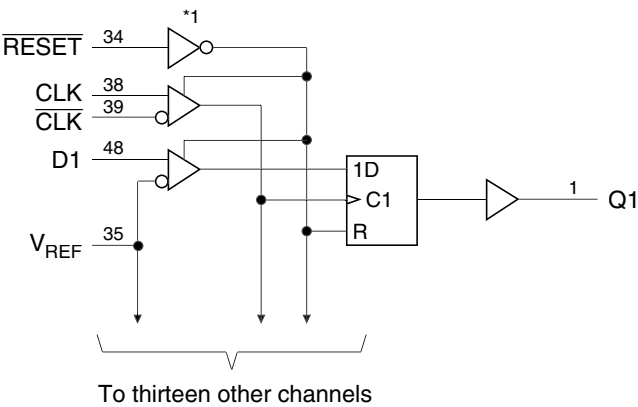
- 1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- 2. This current will flow only when the output is in the high state and $V_O > V_{DDQ}$.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit	Conditions
Supply voltage	V_{CC}	V_{DDQ}	2.5	2.7	V	
Output supply voltage	V_{DDQ}	2.3	2.5	2.7	V	
Reference voltage	V_{REF}	1.15	1.25	1.35	V	$V_{REF} = 0.5 \times V_{DDQ}$
Termination voltage	V_{TT}	$V_{REF} - 40 \text{ mV}$	V_{REF}	$V_{REF} + 40 \text{ mV}$	V	
Input voltage	V_I	0	—	V_{CC}	V	
AC high level input voltage	V_{IH}	$V_{REF} + 310 \text{ mV}$	—	—	V	D
AC low level input voltage	V_{IL}	—	—	$V_{REF} - 310 \text{ mV}$	V	D
DC high level input voltage	V_{IH}	$V_{REF} + 150 \text{ mV}$	—	—	V	D
DC low level input voltage	V_{IL}	—	—	$V_{REF} - 150 \text{ mV}$	V	D
High level input voltage	V_{IH}	1.7	—	$V_{DDQ} + 0.3$	V	$\overline{\text{RESET}}$
Low level input voltage	V_{IL}	-0.3	—	0.7	V	$\overline{\text{RESET}}$
Differential (Common mode range)	V_{CMR}	0.97	—	1.53	V	CLK, $\overline{\text{CLK}}$
input voltage (Minimum peak to peak input)	V_{PP}	360	—	—	mV	CLK, $\overline{\text{CLK}}$
High level output current	I_{OH}	—	—	-20	mA	
Low level output current	I_{OL}	—	—	20	mA	
Operating temperature	T_a	0	—	70	°C	

Note: The $\overline{\text{RESET}}$ input of the device must be held at V_{DDQ} or GND to ensure proper device operation. The differential inputs must not be floating, unless $\overline{\text{RESET}}$ is low.

Logic Diagram



Note: 1. $\overline{\text{RESET}}$ input gate is connected to V_{DDQ} .

Electrical Characteristics

Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	Test Conditions	
Input diode voltage	V _{IK}	2.3	—	—	−1.2	V	I _{IN} = −18 mA	
Output voltage	V _{OH}	2.3 to 2.7	V _{CC} −0.2	—	—	V	I _{OH} = −100 μA	
		2.3	1.95	—	V _{DDQ}		I _{OH} = −16 mA	
	V _{OL}	2.3 to 2.7	—	—	0.2		I _{OL} = 100 μA	
		2.3	0	—	0.35		I _{OL} = 16 mA	
Input current (All inputs)	I _{IN}	2.7	—	—	±5	μA	V _{IN} = 2.7 V or 0	
Quiescent supply current	I _{CC} ^{*2}	2.7	—	—	45	mA	V _{IN} = V _{IH(AC)} or V _{IL(AC)} , I _O = 0	
Standby current	I _{CC (stdy)}	2.7	—	—	10	μA	RESET = GND	
Dynamic operating clock only	I _{CCD} ^{*2}	2.7	—	—	90	μA/ clock MHz	RESET = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)} , CLK and CLK switching 50% duty cycle	
Dynamic operating per each data input	I _{CCD} ^{*2}	2.7	—	—	15	μA/ clock MHz / data input	RESET = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)} , CLK and CLK switching 50% duty cycle. One data input switching at half clock frequency, 50% duty cycle.	
Output high ^{*3}	r _{OH}	2.3 to 2.7	7	—	22 ^{*4}	Ω	I _{OH} = −20 mA	
Output low ^{*3}	r _{OL}	2.3 to 2.7	7	—	22 ^{*4}	Ω	I _{OL} = 20 mA	
r _{OH} − r _{OL} each separate bit ^{*3}	r _{O(A)}	2.5	—	—	4	Ω	I _O = 20 mA, Ta = 25°C	
Input capacitance	Data inputs CLK and CLK RESET	C _{IN}	2.5 ^{*1}	2.5 — 3.0	— — —	3.5 3.5 —	pF	V _I = V _{REF} ±310 mV V _{CMR} = 1.25 V, V _{PP} = 360 mV V _I = V _{CC} or GND

Notes: 1. All typical values are at V_{CC} = 2.5 V, Ta = 25°C.

2. Total I_{CC} (max) = I_{CC} + {I_{CCD} (clock) × f(clock)} + {I_{CCD} (Data) × 1/2f(clock) × 14}

3. This is effective in the case that it did terminate by resistance.

4. See figure. 1, 2

Switching Characteristics

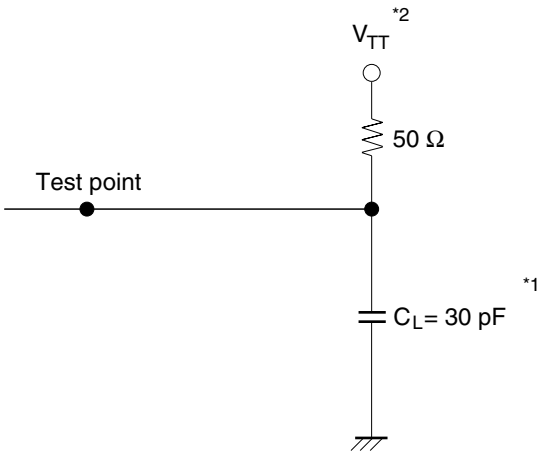
Item		Symbol	V _{CC} = 2.5 ± 0.2 V		Unit	Test Condition
			Min	Max		
Clock frequency ^{*1}		f _{clock}	—	200	MHz	
Setup time	Fast slew rate ^{*4, 6}	t _{su}	0.75	—	ns	Data before CLK↑, CLK↓
	Slow slew rate ^{*5, 6}		0.9	—		
Hold time	Fast slew rate ^{*4, 6}	t _h	0.75	—	ns	Data after CLK↑, CLK↓
	Slow slew rate ^{*5, 6}		0.9	—		
Differential inputs active time		t _{act}	22	—	ns	Data inputs must be low after RESET high.
Differential inputs inactive time		t _{inact}	22	—	ns	Data and clock inputs must be held at valid levels (not floating) after RESET low.
Pulse width		t _w	2.5	—	ns	CLK, CLK “H” or “L”
Output slew ^{*3}		t _{SL}	1	4	volt/ns	

(C_L = 30 pF, R_L = 50 Ω, V_{REF} = V_{TT} = V_{DDQ} × 0.5)

Item	Symbol	V _{CC} = 2.5 ± 0.2 V			Unit	FROM (Input)	TO (Output)
		Min	Typ	Max			
Maximum clock frequency	f _{max}	200	—	—	MHz		
Propagation delay time ^{*2}	t _{PLH} , t _{PHL}	1.1	—	2.8	ns	CLK, CLK	Q
	t _{PHL}	—	—	5.0		RESET	Q

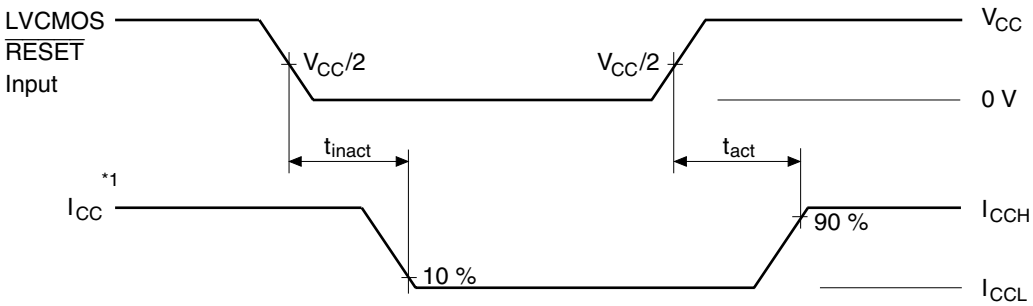
- Notes:
- 1. Although the clock is differential, all timing is relative to CLK going high and CLK going low.
 - 2. This timing relationship is specified into test load (see waveforms – 3, 4) with all of the outputs switching.
 - 3. Assumes into an equivalent, distributed load to the address net structure defined in the application information provided in this specification.
 - 4. For data signal input slew rate ≥ 1 V/ns.
 - 5. For data signal input slew rate ≥ 0.5 V/ns and < 1 V/ns.
 - 6. CLK, CLK signals input slew rates are ≥ 1 V/ns.

Test Circuit

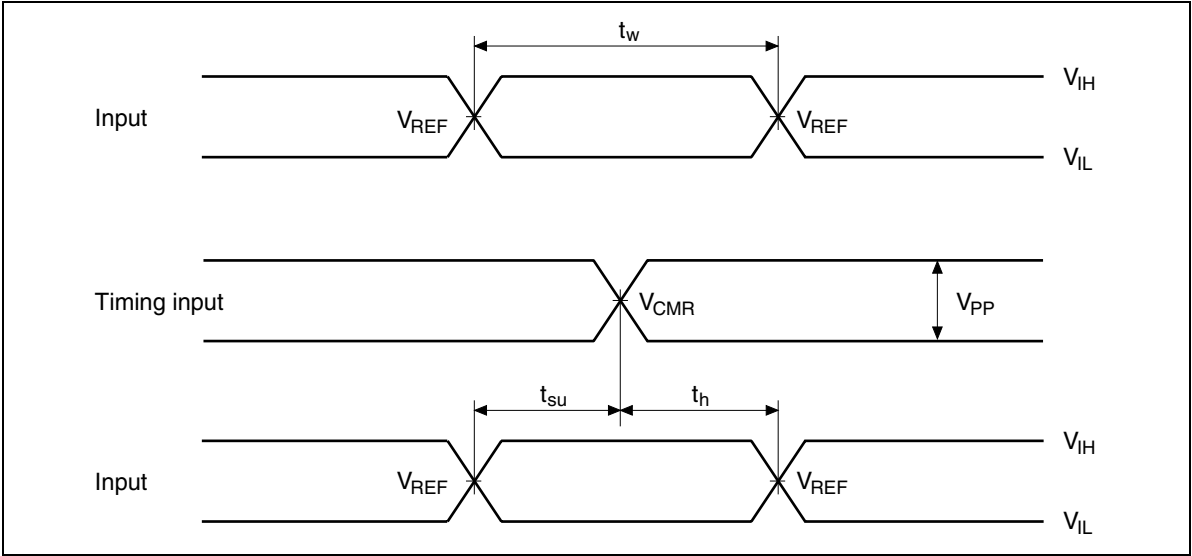


- Notes:
- 1. C_L includes probe and jig capacitance.
 - 2. $V_{TT} = V_{REF} = V_{DDQ} \times 0.5$

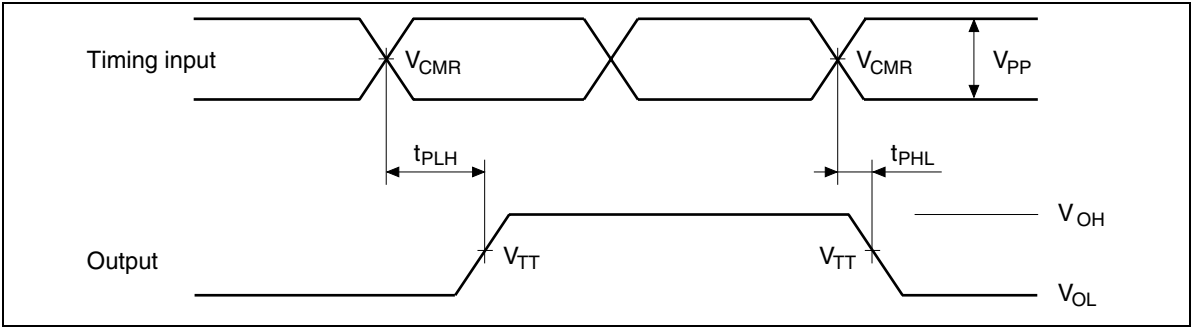
Waveforms – 1



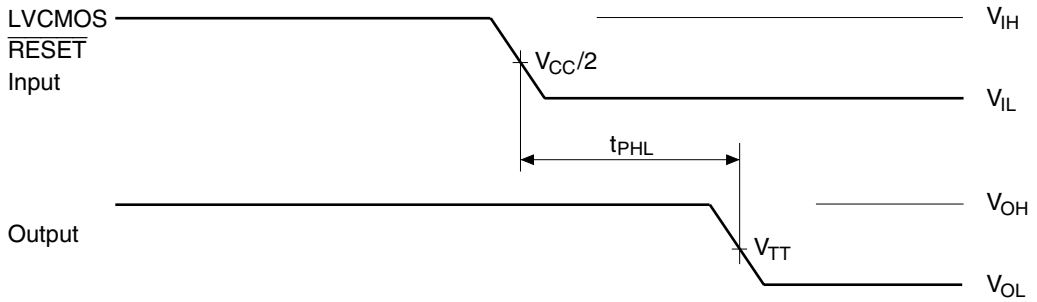
Waveforms – 2



Waveforms – 3



Waveforms – 4



- Notes:
1. I_{CC} tested with clock and data inputs held at V_{CC} or GND, and $I_o = 0$ mA.
 2. All input pulses are supplied by generators having the following characteristics :
 $PRR \leq 10$ MHz, $Z_o = 50 \Omega$, input slew rate = 1 V/ns $\pm 20\%$ (unless otherwise specified).
 3. The outputs are measured one at a time with one transition per measurement.
 4. $V_{TT} = V_{REF} = V_{DDQ}/2$
 5. $V_{IH} = V_{REF} + 310$ mV (AC voltage levels) for differential inputs. $V_{IH} = V_{CC}$ for LVC MOS input.
 6. $V_{IL} = V_{REF} - 310$ mV (AC voltage levels) for differential inputs. $V_{IL} = \text{GND}$ for LVC MOS input.
 7. t_{PLH} and t_{PHL} are the same as t_{pd}

Application Data

• Pull-down

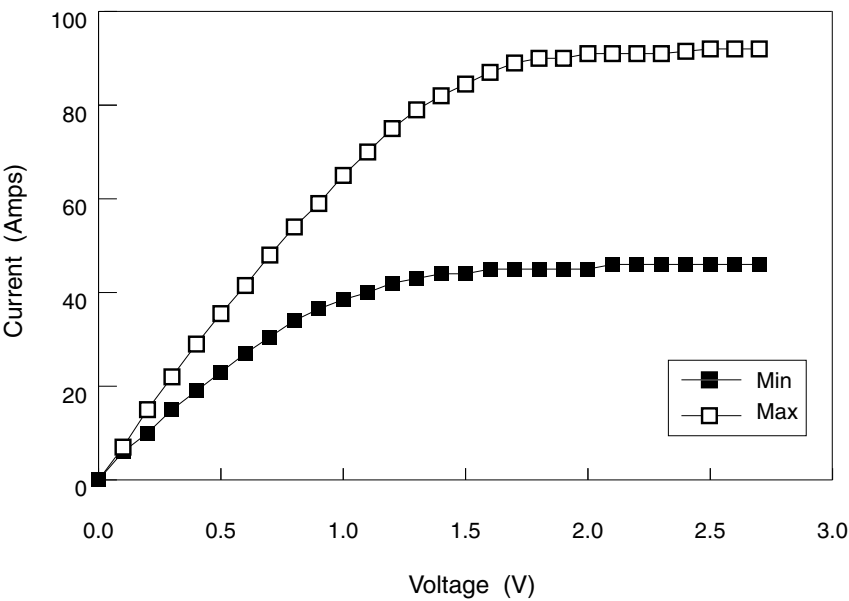


Figure . 1

• Pull-up

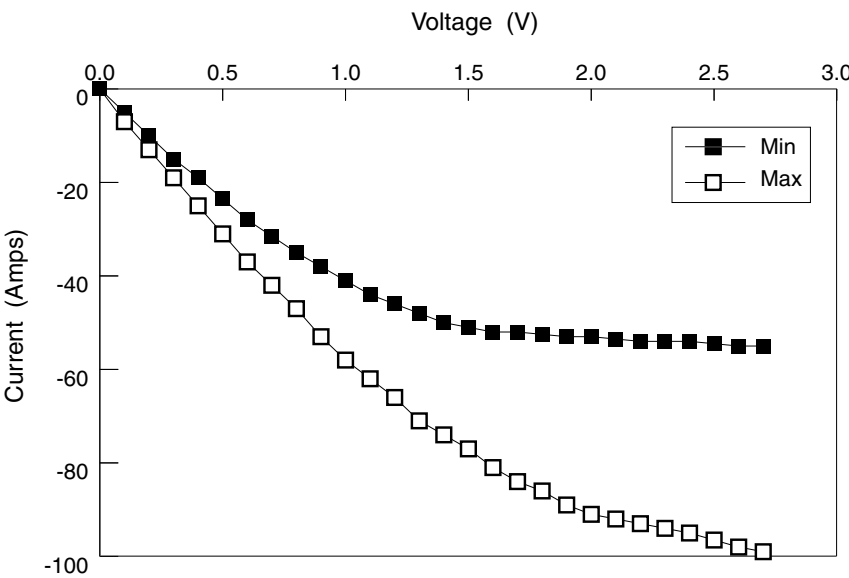


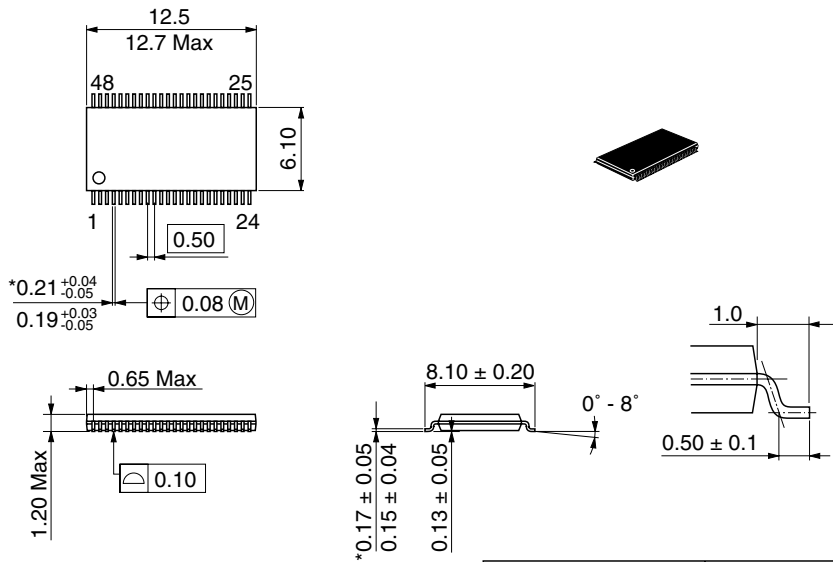
Figure . 2

Curve Data

Voltage (V)	Pull-down		Pull-up	
	I (mA)	I (mA)	I (mA)	I (mA)
	Min	Max	Min	Max
0.0	0	0	0	0
0.1	6	7	-5	-7
0.2	10	15	-10	-13
0.3	15	22	-15	-19
0.4	19	29	-19	-25
0.5	23	35.5	-23.5	-31
0.6	27	41.5	-28	-37
0.7	30.5	48	-31.5	-42
0.8	34	54	-35	-47
0.9	36.5	59	-38	-53
1.0	38.5	65	-41	-58
1.1	40	70	-44	-62
1.2	42	75	-46	-66
1.3	43	79	-48	-71
1.4	44	82	-50	-74
1.5	44	84.5	-51	-77
1.6	45	87	-52	-81
1.7	45	89	-52	-84
1.8	45	90	-52.5	-86
1.9	45	90	-53	-89
2.0	45	91	-53	-91
2.1	46	91	-53.5	-92
2.2	46	91	-54	-93
2.3	46	91	-54	-94
2.4	46	91.5	-54	-95
2.5	46	92	-54.5	-96.5
2.6	46	92	-55	-98
2.7	46	92	-55	-99

Package Dimensions

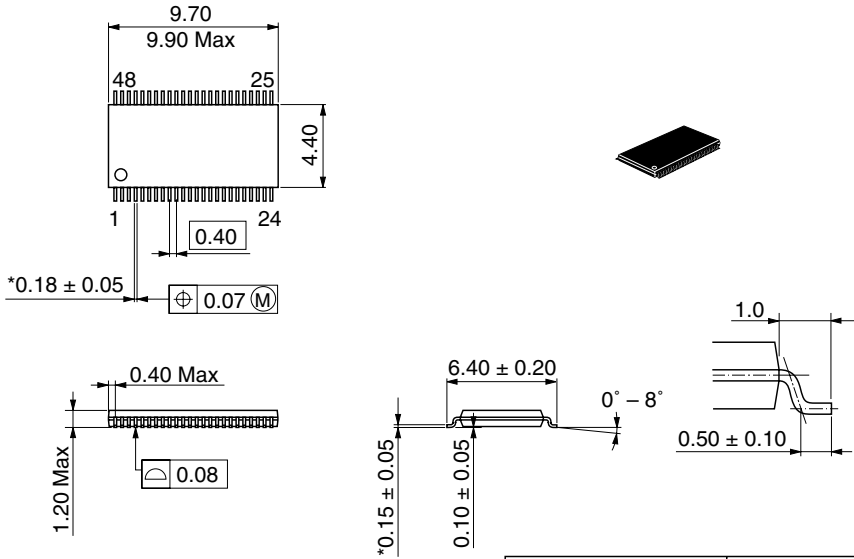
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-48DB
JEDEC	—
EIAJ	—
Mass (reference value)	0.20 g

Unit: mm



*Pd plating

Hitachi Code	TTP-48DEV
JEDEC	—
JEITA	—
Mass (reference value)	—

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